

TO-263-2L Plastic-Encapsulate Diodes

Schottky Barrier Rectifier

MAIN CHARACTERISTICS

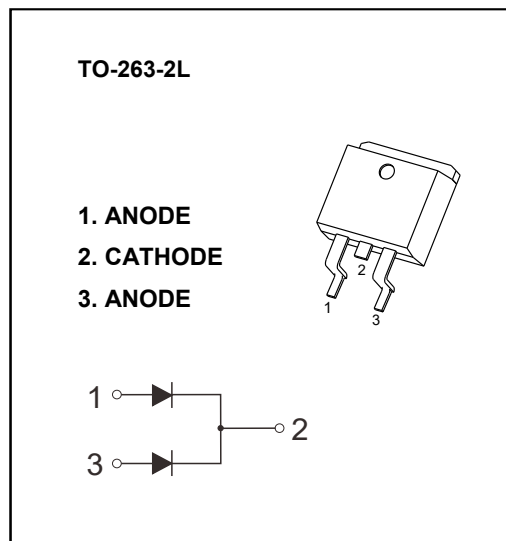
I_O	40(20×2)A
V_{RRM}	100 V
T_j	175 °C
$V_{F(typ)}$	0.66V (@ $T_a=150^{\circ}C$)

FEATURES

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop
- Metal Silicon Junction, Majority Carrier Conduction.
- For Use In Low Voltage,High Frequency Inverters, Free Wheeling and Polarity Protection Applications.

Mechical Data

- Case: TO-263-2L (D²PAK)
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Solder plated, solderable per MIL- STD-202, Method 208
- Polarity: Color band denotes cathode end



MAXIMUM RATINGS ($T_a=25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak repetitive reverse voltage	100	V
V_{RWM}	Working peak reverse voltage		
V_R	DC blocking voltage		
$V_{R(RMS)}$	RMS reverse voltage	70	V
I_O	Average rectified output current	40	A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	300	A
$R_{\theta JC}$	Thermal resistance from junction to case , $T_c=25^{\circ}C$	2.0	$^{\circ}C/W$
$R_{\theta JA}$	Thermal resistance from junction to ambient	75	$^{\circ}C/W$
T	Junction temperature	175	$^{\circ}C$
T_{stg}	Storage temperature	-55~+175	$^{\circ}C$

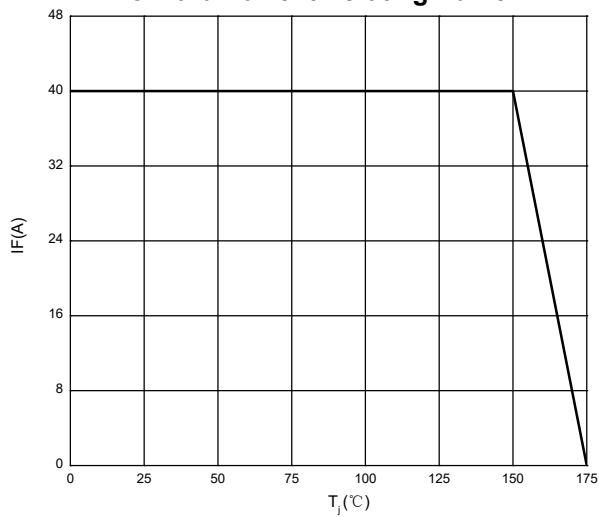
ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=1mA$	100			V
Reverse current	I_R	$V_R=100V$	$T_j=25^{\circ}C$	0.13	1.0	μA
			$T_j=150^{\circ}C$	0.80		mA
Forward voltage	V_F	$I_F=10A$	$T_j=25^{\circ}C$	0.72		V
			$T_j=150^{\circ}C$	0.58		V
		$I_F=20A$	$T_j=25^{\circ}C$	0.80	0.85	V
			$T_j=150^{\circ}C$	0.66		V

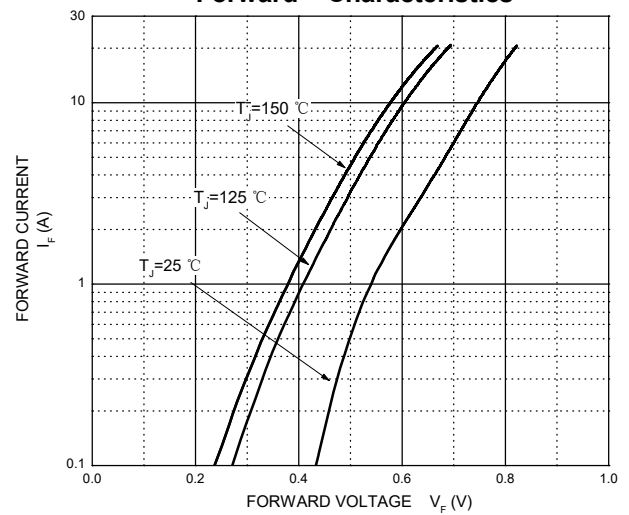
*Pulse test: pulse width $\leq 300\mu s$, duty cycles $\leq 2.0\%$.

Typical Characteristics

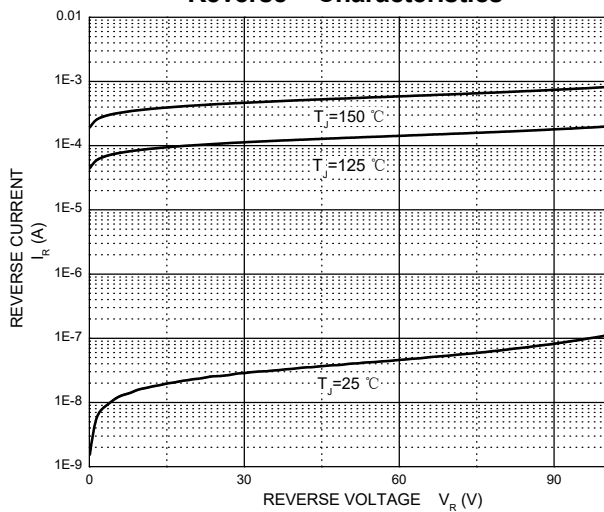
Forward Current Derating Curve



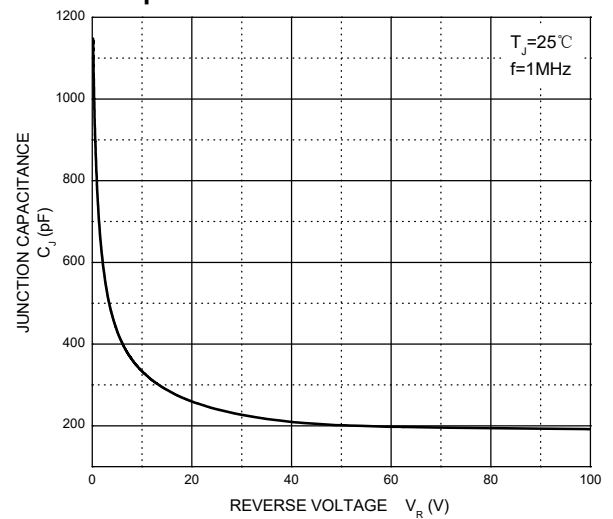
Forward Characteristics



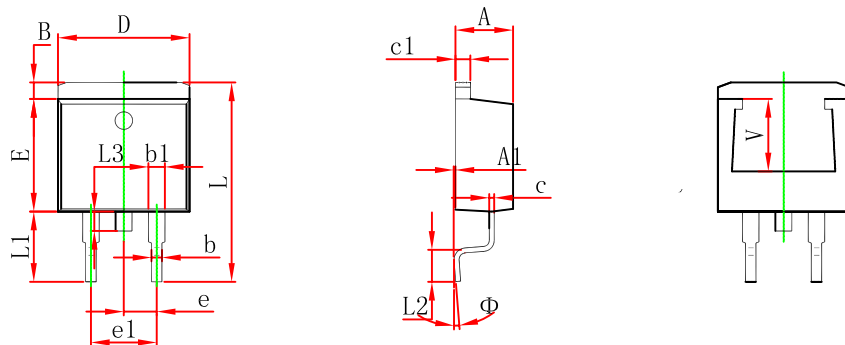
Reverse Characteristics



Capacitance Characteristics Per Diode

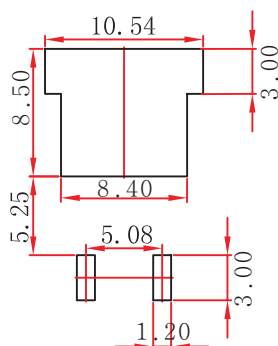


TO-263-2L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.470	4.670	0.176	0.184
A1	0.000	0.150	0.000	0.006
B	1.120	1.420	0.044	0.056
b	0.710	0.910	0.028	0.036
b1	1.170	1.370	0.046	0.054
c	0.310	0.530	0.012	0.021
c1	1.170	1.370	0.046	0.054
D	10.010	10.310	0.394	0.406
E	8.500	8.900	0.335	0.350
e	2.540 TYP.		0.100 TYP.	
e1	4.980	5.180	0.196	0.204
L	14.940	15.500	0.588	0.610
L1	4.950	5.450	0.195	0.215
L2	2.340	2.740	0.092	0.108
L3	1.300	1.700	0.051	0.067
Φ	0° 8°		0° 8°	
V	5.600 REF.		0.220 REF.	

TO-263-2L Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

Ordering Information

Part Number	Package	Shipping Quantity
SBDB40H100CTB	TO-263-2L	800/tape&Reel

Marking Diagram

